# **GS5453**

# 24V, 3A, 700KHZ Synchronous Step-Down DC/DC Converter

## **Product Description**

The GS5453 is a wide input range, high-efficiency and high frequency DC-to-DC step-down switching regulator, capable of delivering up to 3A of output current. It adopts an Adaptive COT control scheme that enables very fast transient response and provides a very smooth transition when the output varies from light load to heavy load. During light load, GS5453 goes into a PFM mode that saves switching loss achieving high efficiency. The adaptive COT control also maintains a constant switching frequency across line and load. An OVP function protects the IC itself and its downstream system against input voltage surges. With this OVP function, the IC can stand off input voltage as high as 24V, making it an ideal solution for industrial applications such as LCD TV, Set Top Box, Portable TV, etc.

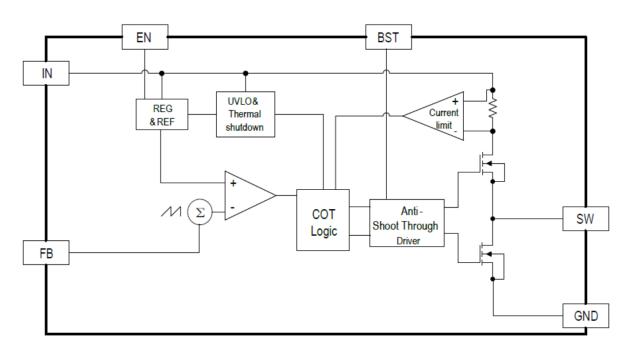
#### **Features**

- Wide 4.5V to 17V Operating Input Range
- 24V Standoff Input Voltage
- Adaptive COT Control
- Ultra-fast Load Transient Response
- High Efficiency PFM mode at light load
- High Efficiency Synchronous operation
- No Load IQ 177uA
- Low Rdson Internal Power FETs
- Capable of Delivering 3A
- No External Compensation Needed
- Thermal Shutdown and UVLO
- Available in SOT-563 Package

## **Applications**

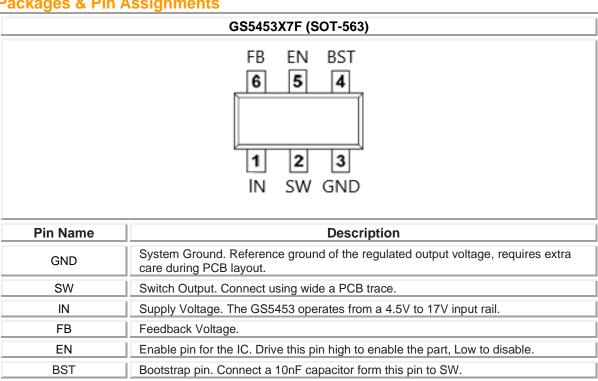
- xDSL Modem
- LCD TV
- Portable Devices
- Set Top Boxes

#### **Functional Block Diagram**

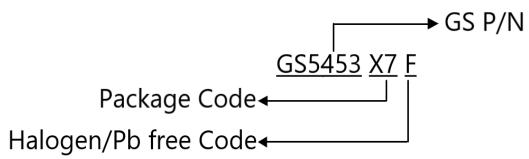




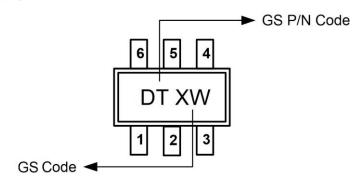
## Packages & Pin Assignments



## **Ordering Information**



#### **Marking Information**



Part Number	Package	Marking	Quantity
GS5453X7F	SOT-563	DTXW	5000 PCS



# **Absolute Maximum Rating**

Symbol	Parameter	Maximum		Unit
VIN, VEN, VSW	Input , Enable and SW Pin Voltage	-0.3 to	24	V
V <sub>BS</sub>	Boost Pin Voltage	-0.3 to Vsw+6		V
V <sub>FB</sub>	Feedback Pin Voltage -0.3 to 6		V	
T <sub>A</sub>	Operating temperature Range -40 to 85		°C	
Tstg	Storage temperature Range	-55 to 150		°C
TLEAD	Lead temperature (Soldering 10S) 260		°C	
HBM (Human Body Mode)		2000		V
ESD	CDM (Charged Device Mode) 1000		0	V
θја	Thermal Resistance Junction to Ambient	SOT-563	130	°C/W

(Note: Exceeding these limits may damage the device. Exposure to absolute maximum ratings conditions for long periods may affect device reliability.)

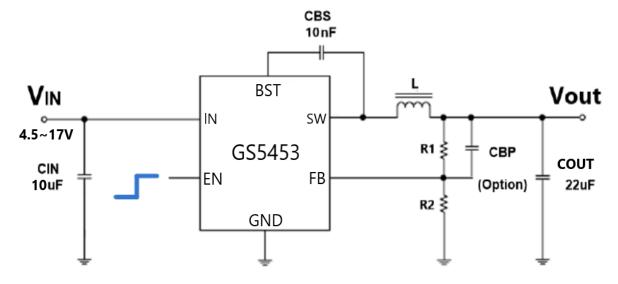
## **Electrical Characteristics**

(Typical values V<sub>IN</sub>=12V, V<sub>OUT</sub>=3.3V with typical T<sub>A</sub>=25°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
$V_{IN}$	Input Voltage Range	-	4.5	-	17	V
V <sub>UVLO</sub>	UVLO Threshold	Rising, Hysteresis=450mV	-	4.05	-	V
V <sub>OVP</sub>	OVP Threshold	Rising, Hysteresis=0.9V	-	18.4	-	V
ΙQ	Supply Current	Vin=12V, V <sub>FB</sub> =0.85V, lout=0A, No Switching	-	177	-	μA
Ishdn	Shutdown Current	-	-	7	14	
$V_{FB}$	Feedback Voltage	-	0.794	0.806	0.818	V
V <sub>FBH</sub>	FB Hiccup Threshold	-	-	0.6	-	V
I <sub>FB</sub>	Feedback Current	-	-	0	1	μA
R <sub>DS(ON)H</sub>	High-Side Switch on Resistance	-	-	85	-	mΩ
R <sub>DS(ON)L</sub>	Low-Side Switch on Resistance	-	-	38	-	mΩ
Tanu	Short Circuit Hiccup Time	On time	-	1.4	-	mS
Тѕсн		Off time	-	4.2	-	mS
I <sub>SW</sub>	Switch Leakage Current	Vin=V <sub>SW</sub> =12V	-	-	10	μA
Fsw	Switching Frequency	-	-	700	-	KHz
I <sub>LIMIT</sub>	High-Side Current Limit	-	-	4.5	-	А
D <sub>MAX</sub>	Maximum Duty Cycle	-	-	87	-	%
$V_{ENH}$	EN Rising Threshold	-	1	1.2	1.4	V
V <sub>ENL</sub>	EN Falling Threshold	-	0.9	1.1	1.3	V
I <sub>EN</sub>	EN Input Current	V <sub>EN</sub> =2V	-	2	6	μA
T <sub>SD</sub>	Thermal Shutdown	Rising, Hysteresis=36°C	-	150	-	°C

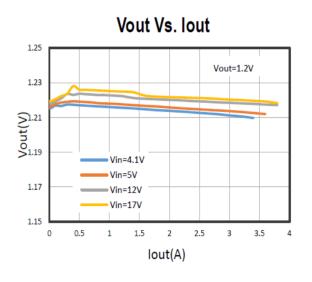


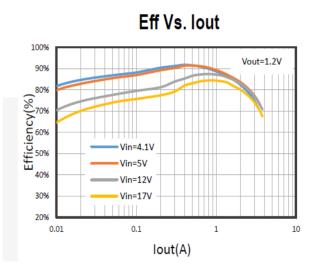
# **Typical Application Circuit**

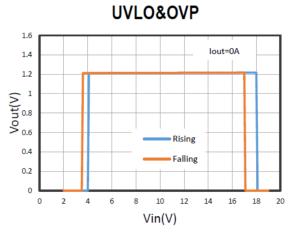


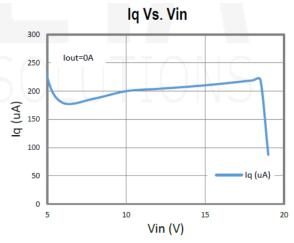
#### **Typical Characteristics**

(Typical values are at T<sub>A</sub>=25° unless otherwise specified)



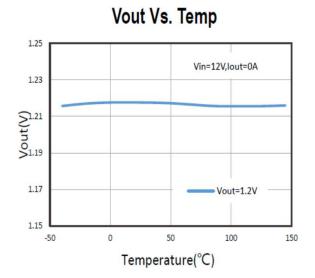


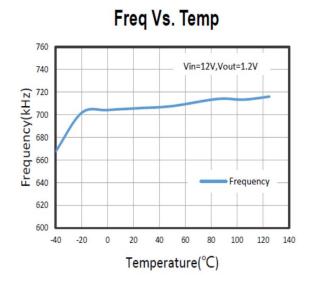


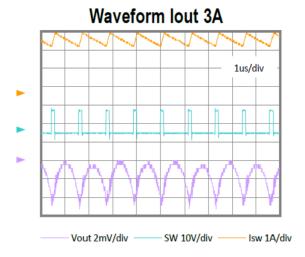


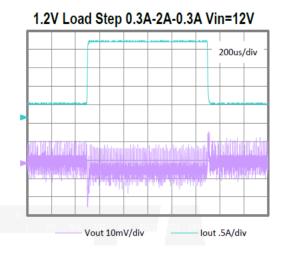


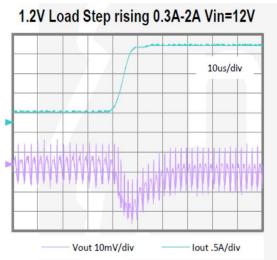
# **Typical Characteristics**(continue)

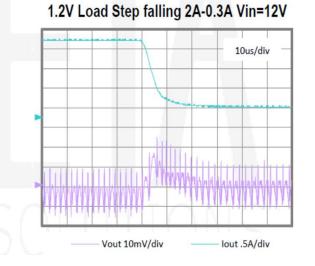












## **Function Description**

The GS5453 is a synchronous buck regulator ICs that integrates the adaptive COT control, top and bottom switches on the same die to minimize the switching transition loss and conduction loss.

GS5453 is a wide input range, high-efficiency and high frequency DC-to-DC step-down switching regulator, capable of delivering up to 3A of output current. It adopts an Adaptive COT control scheme that enables very fast transient response and provides a very smooth transition when the output varies from light load to heavy load. It compares the sum of the FB voltage and a ripple voltage that mimics the voltage due to the output ESR and capacitance. The constant-on-time timer varies with line to achieve relative constant switching frequency across line.

#### **Light Load Operation**

Traditionally, a fixed constant frequency PWM DC-DC regulator always switches even when the output load is small. When energy is shuffling back and forth through the power MOSFET, power is lost due to the finite Rdson of the MOSFET and parasitic capacitances. At light load, this loss is prominent and efficiency is therefore very low. GS5453 goes into a power save mode during light load, thereby extending the range of high efficiency operation.

#### **Enable**

EN is a digital control pin that turns the GS5453 on and off. Drive EN High to turn on the regulator, drive it Low to turn it off. An internal  $1M\Omega$  resistor from EN pin to GND allows EN to float to shut down the chip. Connecting the EN pin through a pull up resistor or shorted EN to IN will automatically turn on the chip whenever plug in IN.

#### **Over Current Protection and Hiccup**

GS5453 has a cycle-by-cycle over current limit for when the inductor current peak value is over the set current limit threshold. When the output voltage drop until FB falls below UV threshold (0.6V), the GS5453 will enter hiccup mode. It will turn off the chip immediately for 6mS. After that, it will try to re-starts as normal for 2mS. After 2mS, if FB is still below UV threshold, then the chip enters hiccup mode again. If FB is higher than UV threshold, it will enter the normal mode.

#### **Over Temperature Protection**

Thermal protection disables the output when the junction temperature rises to approximately 150°C, allowing the device to cool down. When the junction temperature cools to approximately 110°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits regulator dissipation, protecting the device from damage as a result of overheating.



## **Applications Information**

#### **Setting the Output Voltage**

The external resistor divider is used to set the output voltage (see Typical Application on page 4).

Where: V<sub>FB</sub> = 0.806V typically (the internal reference voltage)

Resistors R2 has to be between 1kOhm to 20KOhm.

$$V_{OUT} = V_{FB} x \left(1 + \frac{R_1}{R_2}\right)$$

#### Inductor

A 2.2 $\mu$ H to 4.7 $\mu$ H inductor with a DC current rating of at least 25% percent higher than the maximum load current is recommended for most applications. For highest efficiency, the inductor DC resistance should be less than 15m $\Omega$ . For most designs, the inductance value can be derived from the following equation.

Vout≥3.3V, 2.2µH≤L≤4.7µH.

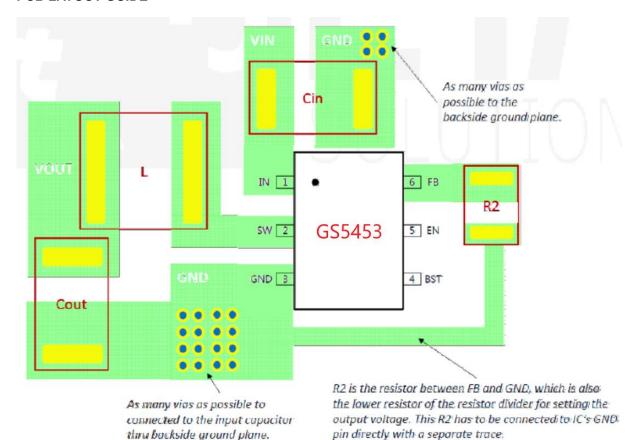
Vout<3.3V, L= 2.2µH.

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L + f_{osc}}$$

Where  $\Delta$  IL is the inductor ripple current. Choose inductor ripple current to be approximately 30% if the maximum load current 3A. The maximum inductor peak current is:

$$I_{L(MAX)} = I_{LOAD} + \frac{\Delta I_L}{2}$$

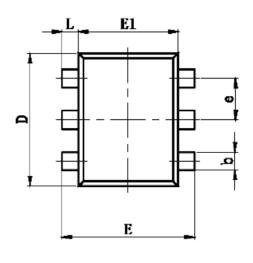
#### **PCB LAYOUT GUIDE**

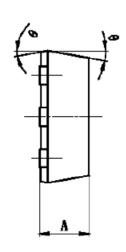


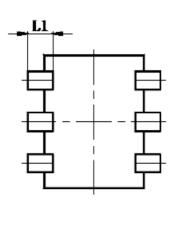


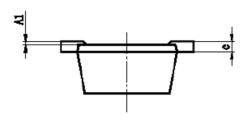
# **Package Dimension**

**SOT-563** 









Dimensions					
CVMDOL	Millimeters		Inches		
SYMBOL	MIN	MAX	MIN	MAX	
Α	0.525	0.600	0.021	0.024	
A1	0.000	0.050	0.000	0.002	
е	0.450	0.550	0.018	0.022	
С	0.090	0.180	0.004	0.007	
D	1.500	1.700	0.059	0.067	
b	0.170	0.270	0.007	0.011	
E1	1.100	1.300	0.043	0.051	
E	1.500	1.700	0.059	0.067	
L	0.100	0.300	0.004	0.012	
L1	0.200	0.400	0.008	0.016	
θ	9° REF		9° REF		



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